
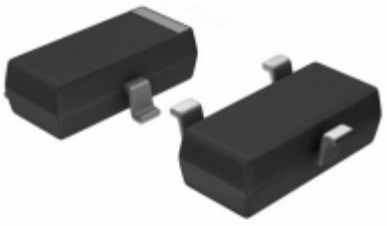





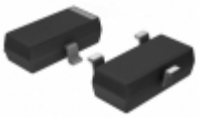
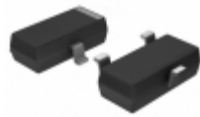
	<h2>SI2366DS-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI2366DS-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 5.8A SOT-23</p> <p><b>Datenblätter:</b>  <a href="#">SI2366DS-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 113390 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI2366DS-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET N-CH 30V 5.8A SOT-23
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	113390 pcs Stock
detaillierte Beschreibung	N-Channel 30V 5.8A (Tc) 1.25W (Ta), 2.1W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.1W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.8A (Tc)
Rds On (Max) @ Id, Vgs	36 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	335pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2366DS-T1-GE3-ND
































SI2366DS-T1-GE3 ist neu im Original, Suche SI2366DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2366DS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2366DS-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI2369DS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 7.6A TO-236</p>	 <p><b>SI2366DS-T1-E3</b> VISHAY SI2366DS-T1-E3 VISHAY</p>	 <p><b>SI2367DS-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 3.8A SOT-23</p>	 <p><b>SI2367DS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 3.8A SOT-23</p>
 <p><b>SI2366DS-T1-GE</b> VISHAY SI2366DS-T1-GE VISHAY</p>	 <p><b>SI2366DS-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 30V 5.8A SOT-23</p>	 <p><b>SI2365EDS-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 5.9A TO-236</p>	 <p><b>SI2369DS-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 7.6A TO-236</p>

### heiße Teile

Mehr

 SI2342DS-T1-GE3	 SI2342DS-T1-GE3	 SI2343ADS-T1-GE3	 SI2343CDS	 SI2343CDS-T1-E3
 SI2343CDS-T1-GE3	 SI2343CDS-T1-GE3	 SI2343DS-T1-E3	 SI2343DS-T1-E3	 SI2343DS-T1-GE3
 SI2343DS-T1-GE3	 SI2344DS-E3	 SI2347DS-T1-GE3	 SI2347DS-T1-GE3	 SI2351DS-T1-E3
 SI2351DS-T1-E3	 SI2351DS-T1-GE3	 SI2351DS-T1-GE3	 SI2356DS-T1-GE3	 SI2356DS-T1-GE3
 SI2365EDS	 SI2365EDS-T1-GE3	 SI2365EDS-T1-GE3	 SI2366DS-T1-E3	 SI2366DS-T1-GE
 SI2366DS-T1-GE3	 SI2367DS-T1-E3	 SI2367DS-T1-GE3	 SI2367DS-T1-GE3	 SI2369DS-T1-GE3
 SI2369DS-T1-GE3	 SI2371EDS-T1-GE3	 SI2371EDS-T1-GE3	 SI2372DS-T1-E3	 SI2372DS-T1-GE3
 SI2372DS-T1-GE3	 SI2374DS-T1-GE3	 SI2374DS-T1-GE3	 SI2377DS-T1-GE3	 SI2377EDS
 SI2377EDS-T1-E3	 SI2377EDS-T1-GE3	 SI2377EDS-T1-GE3	 SI2392ADS-T1-E3	 SI2392ADS-T1-GE3
 SI2392ADS-T1-GE3	 SI2392DS-T1-GE3	 SI2392DS-T1-GE3	 SI2399CDS-T1-GE3	 SI2399DS-T1-GE3

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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